

SEMIPONT® 1

Controllable Bridge Rectifiers

SKBH 28

Features

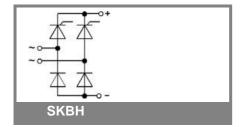
- · Sturdy isolated metal baseplate
- · Fast-on terminals with solder tips
- · Suitable for wave soldering
- · High surge current rating
- UL recognized, file no. E 63 532

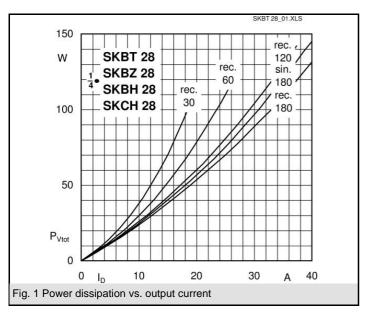
Typical Applications

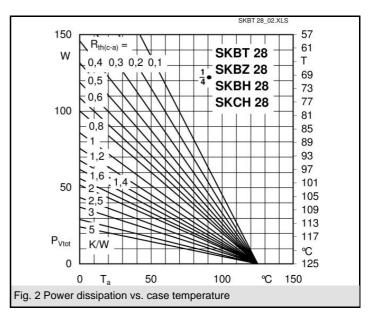
- Controllable single phase rectifierDC power supplies
- DC motor controllers
- · DC motor field controllers
- 1) Painted metal shield of minimum 250 x 250 x 1 mm: $R_{th(c-a)}$ = 1,85 K/W
- 2) Freely suspended or mounted on insulator

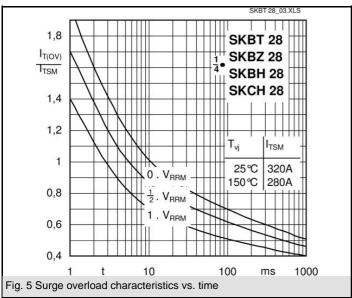
V _{RSM}	V_{RRM}, V_{DRM}	I _D = 28 A (full conduction)
V	V	(T _c = 89 °C)
600	600	SKBH 28/06
800	800	SKBH 28/08
1200	1200	SKBH 28/12
1400	1400	SKBH 28/14

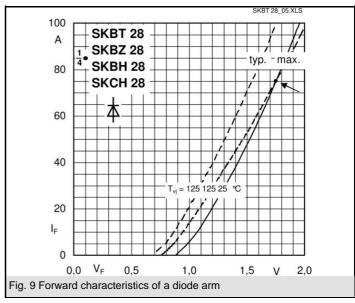
Symbol	Conditions	Values	Units
I _D	T _c = 85 °C	30	Α
	T _a = 45 °C; chassis ¹⁾	13	Α
	T _a = 45 °C; P5A/100	15	Α
	T _a = 45 °C; P13A/125	16	Α
	T _a = 45 °C; P1A/120	23	Α
I _{TSM} , I _{FSM}	T_{vj} = 25 °C; 10 ms	320	Α
	$T_{vj} = 125 ^{\circ}\text{C}; 10 \text{ms}$	280	Α
i²t	$T_{vj} = 25 ^{\circ}\text{C}; 8,3 \dots 10 \text{ms}$	510	A²s
	T_{vj} = 125 °C; 8,3 10 ms	390	A²s
V_T	$T_{vj} = 25 ^{\circ}\text{C}; I_{T} = 75 \text{A}$	max. 2,25	V
$V_{T(TO)}$	T _{vj} = 125 °C;	max. 1	V
r _T	T _{vj} = 125 °C	max. 16	mΩ
I_{DD} ; I_{RD}	T_{vj} = 125 °C; V_{DD} = V_{DRM} ; V_{RD} = V_{RRM}	max. 8	mA
t _{gd}	$T_{vj} = 25 ^{\circ}\text{C}; I_{G} = 1 \text{A}; di_{G}/dt = 1 \text{A}/\mu\text{s}$	1	μs
t _{gr}	$V_D = 0.67 \cdot V_{DRM}$	1	μs
(dv/dt) _{cr}	T _{vi} = 125 °C	max. 500	V/µs
(di/dt) _{cr}	$T_{vi} = 125 ^{\circ}\text{C}; f = 50 \text{Hz}$	max. 50	A/µs
t _q	$T_{vj} = 125 ^{\circ}\text{C}$; typ.	80	μs
I _H	T_{vj} = 25 °C; typ. / max.	50 / 150	mA
IL	T_{vj} = 25 °C; R_G = 33 Ω	100 / 300	mA
V_{GT}	$T_{vj} = 25 ^{\circ}\text{C}; \text{d.c.}$	min. 2	V
I _{GT}	$T_{vj} = 25 ^{\circ}\text{C}; \text{d.c.}$	min. 100	mA
V_{GD}	$T_{vj} = 125 ^{\circ}\text{C}; \text{d.c.}$	max. 0,25	V
I_{GD}	T_{vj} = 125 °C; d.c.	max. 3	mA
R _{th(j-c)}	per thyristor / diode	1,8	K/W
,	total	0,45	K/W
R _{th(c-s)}	total	0,1	K/W
$R_{th(j-a)}$	total ²⁾	15	K/W
T_{vj}		- 40 + 125	°C
T_{stg}		- 40 + 125	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 (3000)	V
M_s	case to heatsink	2	Nm
M _t		n.a.	Nm
m		66	g
Case	SKBH	G 23	

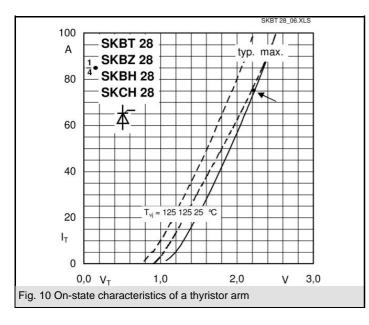


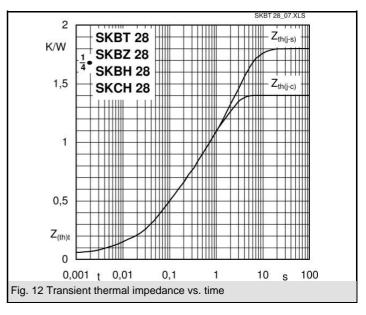


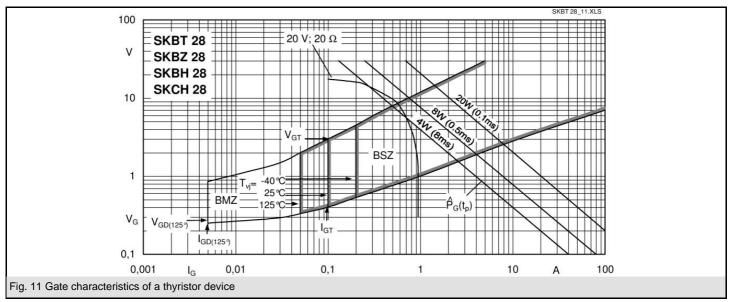


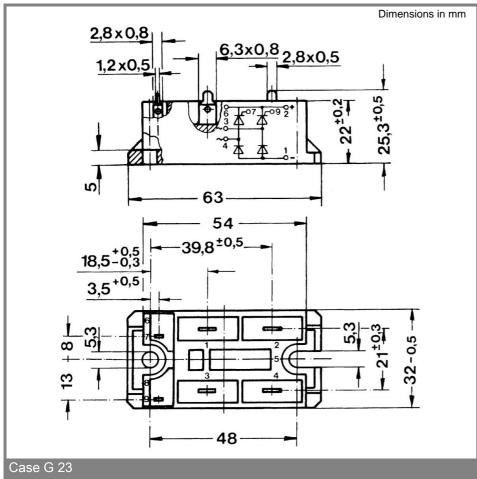












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